## IN THE CLAIMS

Please cancel claims 6, 7, 13, 14, 18, 19, 23 and 24 without prejudice and amend the claims as follows:

1. (currently amended) A method for producing a quartz glass jig, said method comprising: processing a quartz glass raw material into a desired shape of the quartz glass jig by a treatment including fire working, annealing a product of the desired shape so as to remove stress therein, and performing a cleaning treatment on the product to obtain a final product, wherein a gas phase etching step and a gas phase purification step are performed on a surface layer of the product after the annealing but before the cleaning treatment, and wherein the gas phase purification step is carried out continuously after the gas phase etching step.

wherein the gas phase etching step is performed in a fluorine-containing gaseous atmosphere that contains at least one gas selected from the group consisting of  $C_xF_y$ ,  $Cl_xF_y$ ,  $N_xF_y$ ,  $Si_xF_y$ ,  $S_xF_y$  (where,  $10 \ge x \ge 1$  and  $10 \ge y \ge 1$ ),  $CHF_3$ , HF, and  $F_2$ , and

wherein the gas phase purification step comprises performing a high temperature heat treatment in a temperature range of from 800 to 1300 °C in a gaseous atmosphere containing Cl.

2. (currently amended) A method for producing a quartz glass jig, said method comprising: processing a quartz glass raw material into a desired shape of the quartz glass jig by a treatment including fire working, annealing a product of the desired shape so as to remove stress therein,

and performing a cleaning treatment on the product to obtain a final product, wherein a gas phase etching step and a gas phase purification step are performed on a surface layer of the product after the annealing but before the cleaning treatment, and wherein the gas phase purification step is carried out simultaneously with the gas phase etching step.

wherein the gas phase etching step is performed in a fluorine-containing gaseous atmosphere that contains at least one gas selected from the group consisting of  $C_xF_y$ ,  $Cl_xF_y, N_xF_y, Si_xF_y, S_xF_y \text{ (where, } 10 \geq x \geq 1 \text{ and } 10 \geq y \geq 1 \text{), } CHF_3, HF, \text{ and } F_2, \text{ and}$  wherein the gas phase purification step comprises performing a high temperature heat treatment in a temperature range of from 800 to 1300 °C in a gaseous atmosphere containing Cl.

3. (currently amended) A method for producing a quartz glass jig, said method comprising: processing a quartz glass raw material into a desired shape of the quartz glass jig by a treatment including fire working, annealing the quartz glass jig so as to remove stress therein, and performing a cleaning treatment on the product to obtain a final product, wherein a gas phase etching step and a gas phase purification step are performed on a surface layer of the product simultaneously with the annealing, and wherein the gas phase purification step is carried out continuously after the gas phase etching step.

wherein the gas phase etching step is performed in a fluorine-containing gaseous atmosphere that contains at least one gas selected from the group consisting of  $C_xF_y$ ,  $Cl_xF_y, N_xF_y, Si_xF_y, S_xF_y \text{ (where, } 10 \geq x \geq 1 \text{ and } 10 \geq y \geq 1), CHF_3, HF, \text{ and } F_2, \text{ and}$  wherein the gas phase purification step comprises performing a high temperature

heat treatment in a temperature range of from 800 to 1300 °C in a gaseous atmosphere containing Cl.

4. (currently amended) A method for producing a quartz glass jig, said method comprising: processing a quartz glass raw material into a desired shape of the quartz glass jig by a treatment including fire working, annealing a product of the desired shape so as to remove stress therein, and performing a cleaning treatment on the product to obtain a final product, wherein a gas phase etching step and a gas phase purification step are performed on a surface layer of the product simultaneously with the annealing, and wherein the gas phase purification step is carried out simultaneously with the gas phase etching step.

wherein the gas phase etching step is performed in a fluorine-containing gaseous atmosphere that contains at least one gas selected from the group consisting of  $C_xF_y$ ,  $Cl_xF_y, N_xF_y, Si_xF_y, S_xF_y \text{ (where, } 10 \geq x \geq 1 \text{ and } 10 \geq y \geq 1), CHF_3, HF, \text{ and } F_2, \text{ and}$  wherein the gas phase purification step comprises performing a high temperature heat treatment in a temperature range of from 800 to 1300 °C in a gaseous atmosphere containing Cl.

- 5. (Currently amended) A method for producing a quartz glass jig as claimed in Claim 1, wherein the gas phase etching step is performed in a temperature range of from 0 °C to 1300 °C in the fluorine-containing a gaseous atmosphere containing fluorine (F).
- 6. (Canceled).

7. (Canceleu).			
8. (Currently amended) A meth	nod for producing a qu	artz glass jig as claimo	ed in Claim <b>1</b> 7
wherein the gaseous atmosphere	containing Cl is HCl,	Cl <sub>2</sub> , or a combination	of HCl and Cl <sub>2</sub>
0 (Cumontly amonded) A math	and for muchusing a sur-	outo alono ∷o ao aloimo	od in Claim 5
9. (Currently amended) A meth	lod for producing a qui	artz glass jig as ciaim	ed in Claim 5,
wherein the <b>fluorine-containing</b>	gaseous atmosphere e	containing F further in	ncludes a gas
containing H.			
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10 (01 1)			
10. (Canceled)			•
11. (Canceled)			
12. (Currently amended) A med	thod for producing a q	uartz glass jig as clain	ned in Claim 2,
wherein the gas phase etching ste	ep is performed in a te	mperature range of fr	om 0 °C to
1300 °C in the fluorine-contain	ing a gaseous atmosph	nere <b>containing fluor</b>	i <del>ne (F)</del> .
13. (Canceled).			
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14. (Canceled).			
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- 15. (Currently amended) A method for producing a quartz glass jig as claimed in Claim **2** 14, wherein the gaseous atmosphere containing Cl is HCl, Cl<sub>2</sub>, or a combination of HCl and Cl<sub>2</sub>.
- 16. (Currently amended) A method for producing a quartz glass jig as claimed in Claim 12, wherein the **fluorine-containing** gaseous atmosphere **containing** F further includes a gas containing H.
- 17. (Currently amended) A method for producing a quartz glass jig as claimed in Claim 3, wherein the gas phase etching step is performed in a temperature range of from 0 °C to 1300 °C in the fluorine-containing a gaseous atmosphere containing fluorine (F).
- 18. (Canceled).
- 19. (Canceled).
- 20. (Currently amended) A method for producing a quartz glass jig as claimed in Claim **3 19**, wherein the gaseous atmosphere containing Cl is HCl, Cl<sub>2</sub>, or a combination of HCl and Cl<sub>2</sub>.
- 21. (Currently amended) A method for producing a quartz glass jig as claimed in Claim 17, wherein the **fluorine-containing** gaseous atmosphere **containing** F further includes a gas containing H.

- 22. (Currently amended) A method for producing a quartz glass jig as claimed in Claim 4, wherein the gas phase etching step is performed in a temperature range of from 0 °C to 1300 °C in the fluorine-containing a gaseous atmosphere containing fluorine (F).
- 23. (Canceled).
- 24. (Canceled).
- 25. (Currently amended) A method for producing a quartz glass jig as claimed in Claim **424**, wherein the gaseous atmosphere containing Cl is HCl, Cl<sub>2</sub>, or a combination of HCl and Cl<sub>2</sub>.
- 26. (Currently amended) A method for producing a quartz glass jig as claimed in Claim 17, wherein the **fluorine-containing** gaseous atmosphere **containing** F further includes a gas containing H.